



Narrow Band Low Noise Amplifier 825MHz~835MHz

- High Gain 40dB
- Applicable for base station, repeaters of cellular network
- LMDS multi-carrier operation
- High Peak to average handle capability
- High Linearity and low noise figure
- Lower Noise Figure unit available upon request



Electrical Specifications			
Frequency Range:	825MHz-835MHz	P1dB	+22dBm
Noise Figure:	1.0dB typ. 1.35dB Max *	Out IP3:	+32dBm
Gain:	40dB	Output VSWR:	1.5 : 1
Flatness:	+/-0.5dB	Input VSWR:	1.5 : 1
Input Power	-18dBm (Max) **	DC Voltage:	+12V/350mA max ***
Mechanical and Environmental Specifications			
Operation Temperature:	-40°C to 85°C base plate	Mechanical shock	30G, 11mSec half sin wave, 3 axis both directions
Vibration:	14.2g RMS (15-2000Hz) functional	Humidity	95% relative humidity, 65°C 96Hour
	16.2g RMS (15-2000Hz) endurance, 1 hour per axis	MTBF	50000 hour min
Connectors:	RF SMA-F Removable	Case:	Conductive no paint
	Supply RFI filter solder Pin	Dimension Size (L x W x H):	3.27" x 1.38" x 0.65" 83mm x 35mm x 16.5 mm

*Contact manufacture for lower NF solution

** Input over drive protection available upon request

*** DC Reverse protection available upon request

Heat Sink required during operation.

